2/72/A

DECLARATION FOR PATENT APPLICATION

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name.

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled

SEMICONDUCTOR DEVICE WITH A MULTI-LEVEL INTERCONNECT STRUCTURE AND METHOD FOR MAKING the specification of which is attached hereto unless the following box is checked: Nov. 19, 2003 as United States Application Number 10/716,948 Х was filed on or PCT International Application Number and was amended on (if applicable) I hereby state that I have reviewed and understand the contents of the above identified specification, ... including the claims, as amended by any amendment referred to above. I acknowledge the duty to disclose information which is material to patentability as defined in 37 CFR \$1.56. including for continuation-in-part applications, material information which became available between the filing date of the prior application and the national or PCT international filing date of the continuation-in-part application. I hereby claim foreign priority benefits under 35 U.S.C. 8119(a)-(d) or 8365(b), of any foreign application(s) for patent or inventor's certificate, or 8365(a) of any PCT international application which designated at least one country other than the United States, listed below and have also identified below, by checking the box, any foreign application for patent or inventor's certificate, or any PCT international application, having a filing date before that of the application on which priority is claimed: Prior Foreign Application(s) Priority Claimed 091134054 Taiwan 22/Nov./2002 (Number) (Day/Month/Year Filed) (Country) No (Number) (Country) (Day/Month/Year Filed) No (Number) (Country) (Day/Month/Year Filed) I hereby claim the benefit under 35 U.S.C. 8119(e) of any United States provisional application(s) listed below. (Application Number) (Filing Date) (Application Number) (Filing Date) (Application Number) (Filing Date) Based on Form PTO/SB/01 (6-95) (F-66) Patent and Trademark Office: U.S. DEPARTMENT OF COMMERCE

الإضاء والمعا

I hereby claim the benefit und International application designated claims of this application is not of manner provided by the first paramaterial to patentability as defi- application and the national or P	ting the United State disclosed in the prior ragraph of 35 U.S.C. ned in 37 CFR \$1.5	es listed below and United States appliable. § 112, I acknowled which became a	I, insofar as the subject matter cation or PCT International a dge the duty to disclose infor available between the filing of	er of each of the application in the rmation which is
(Application Serial No.)	(Filing Date)		(Status - patented, pendi	ing, abandoned)
(Application Serial No.)	(Filing Date)		(Status - patented, pending, abandoned)	
	emark Office conne No. 30,173/Willi No. 30,625/Dou No. 18,510/Jerom & SOFFEN, LLP icas	cted therewith: Lam O. Gray, II Liglas A. Miro Lie M. Berliner Robert C.		
information and belief are believ willful false statements and the li Title 18 of the United States Coo or any patent issued thereon. Full name of sole or first inventor Yu-Nung SHEN	ke so made are puni	shable by fine or in	nprisonment, or both, under	Section 1001 of
Inventor's signature				Data
Inventor's signature	00		Feb. 19, 2004	Date
Residence: City	State	Country	Citizenship	
4F, No. 52, Sec. 2, C	hung-Shan N. Rd.	, Taipei City,	Taiwan	
Mailing Address Same as residence				
Full name of second joint inventor, if	any			
Second Inventor's signature		,		Date
Residence: City	State	Country	Citizenship	
Mailing Address				

Additional inventors are being named on separately numbered sheets attached hereto